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- Independent Registers for A and B Buses
- Multiplexed Real-Time and Stored Data
- Choice of True or Inverting Data Paths
- Choice of 3-State or Open-Collector Outputs
- Package Options Include Plastic Small-Outline (DW) Packages, Ceramic Chip Carriers (FK), and Standard Plastic (NT) and Ceramic (JT) 300-mil DIPs

DEVICE	OUTPUT	LOGIC
SN54ALS646, SN74ALS646A, 'AS646	3 state	True
SN54ALS648, SN74ALS648A, SN74AS648	3 state	Inverting

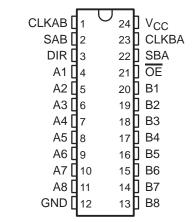
description

These devices consist of bus-transceiver circuits with 3-state or open-collector outputs, D-type flip-flops, and control circuitry arranged for multiplexed transmission of data directly from the data bus or from the internal storage registers. Data on the A or B bus is clocked into the registers on the low-to-high transition of the appropriate clock (CLKAB or CLKBA) input. Figure 1 illustrates the four fundamental bus-management functions that can be performed with the octal bus transceivers and registers.

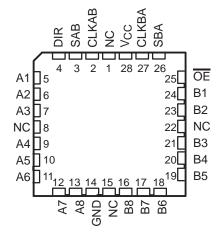
Output-enable (OE) and direction-control (DIR) inputs control the transceiver functions. In the transceiver mode, data present at the high-impedance port may be stored in either or both registers.

The select-control (SAB and SBA) inputs can multiplex stored and real-time (transparent mode)

SN54ALS646, SN54ALS648, SN54AS646 . . . JT PACKAGE SN74ALS646A, SN74ALS648A, SN74AS646, SN74AS648 . . . DW OR NT PACKAGE (TOP VIEW)



SN54ALS646, SN54ALS648, SN54AS646 . . . FK PACKAGE (TOP VIEW)



NC - No internal connection

data. The circuitry used for select control eliminates the typical decoding glitch that occurs in a multiplexer during the transition between stored and real-time data. DIR determines which bus receives data when \overline{OE} is low. In the isolation mode (\overline{OE} high), A data may be stored in one register and/or B data may be stored in the other register.

When an output function is disabled, the input function is still enabled and can be used to store and transmit data. Only one of the two buses, A or B, may be driven at a time.

The -1 version of the SN74ALS646A is identical to the standard version, except that the recommended maximum I_{OL} in the -1 version is increased to 48 mA. There are no -1 versions of the SN54ALS646, SN54ALS648, or SN74ALS648A.

The SN54ALS646, SN54ALS648, and SN54AS646 are characterized for operation over the full military temperature range of –55°C to 125°C. The SN74ALS646A, SN74ALS648A, SN74AS646, and SN74AS648 are characterized for operation from 0°C to 70°C.



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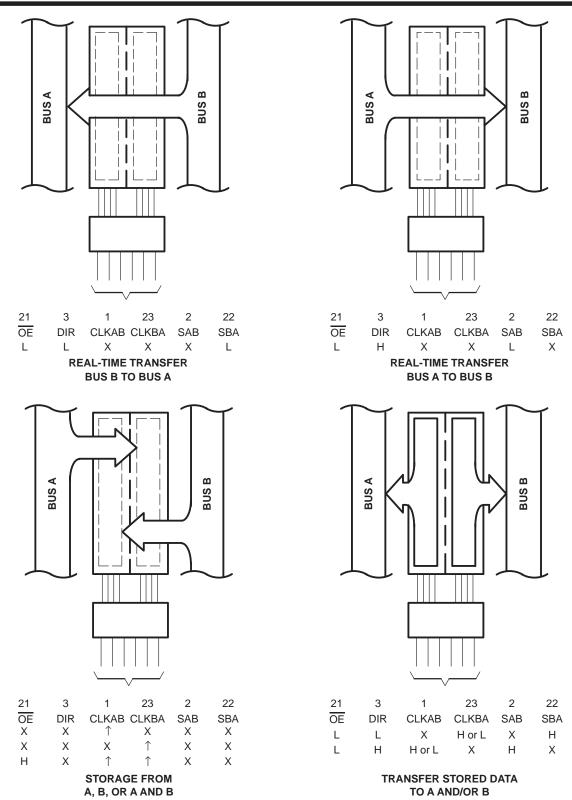


Figure 1. Bus-Management Functions

Pin numbers shown are for the DW, JT, and NT packages.



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Function Tables

SN54ALS646, SN54AS646, SN74ALS646A, SN74AS646

		INP	UTS			DAT	A I/O	OPERATION OR FUNCTION
ŌĒ	DIR	CLKAB	CLKBA	SAB	SBA	A1-A8	B1-B8	OPERATION OR FUNCTION
Х	Χ	1	Х	Х	Χ	Input	Unspecified [†]	Store A, B unspecified [†]
Х	Χ	Χ	\uparrow	Χ	Χ	Unspecified [†]	Input	Store B, A unspecified [†]
Н	Х	1	↑	Х	Х	Input	Input	Store A and B data
Н	Χ	H or L	H or L	Χ	Χ	Input disabled	Input disabled	Isolation, hold storage
L	L	Х	Х	Х	L	Output	Input	Real-time B data to A bus
L	L	Χ	H or L	Χ	Н	Output	Input	Stored B data to A bus
L	Н	Х	Х	L	Χ	Input	Output	Real-time A data to B bus
L	Н	H or L	Χ	Н	Χ	Input	Output	Stored A data to B bus

[†]The data output functions can be enabled or disabled by various signals at $\overline{\text{OE}}$ and DIR. Data input functions are always enabled; i.e., data at the bus terminals is stored on every low-to-high transition of the clock inputs.

SN54ALS648, SN74ALS648A, SN74AS648

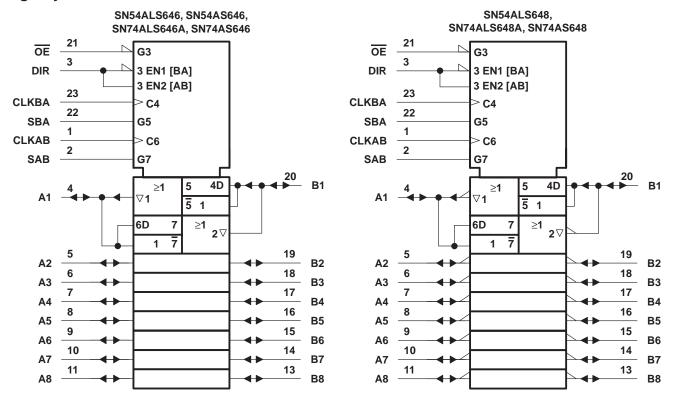
		INP	UTS			DAT	A I/O	OPERATION OR FUNCTION
OE	DIR	CLKAB	CLKBA	SAB	SBA	A1-A8	B1-B8	OPERATION OR FUNCTION
Х	Х	1	Χ	Х	Х	Input	Unspecified [†]	Store A, B unspecified [†]
Х	Χ	Χ	\uparrow	X	Χ	Unspecified [†]	Input	Store B, A unspecified [†]
Н	Х	1	↑	Х	Χ	Input	Input	Store A and B data
Н	Χ	H or L	H or L	Χ	Χ	Input disabled	Input disabled	Isolation, hold storage
L	L	Х	Х	Х	L	Output	Input	Real-time B data to A bus
L	L	Χ	H or L	Χ	Н	Output	Input	Stored \overline{B} data to A bus
L	Н	Х	Х	L	Χ	Input	Output	Real-time \overline{A} data to B bus
L	Н	H or L	Χ	Н	X	Input	Output	Stored \overline{A} data to B bus

[†] The data output functions can be enabled or disabled by various signals at $\overline{\text{OE}}$ and DIR. Data input functions are always enabled; i.e., data at the bus terminals is stored on every low-to-high transition of the clock inputs.



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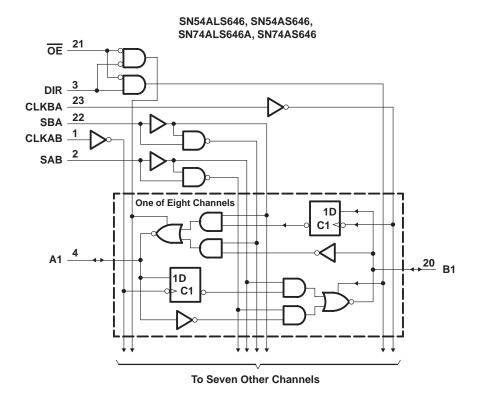
logic symbols†

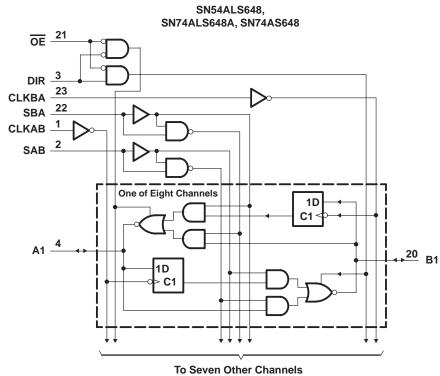


[†]These symbols are in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12. Pin numbers shown are for the DW, JT, and NT packages.



logic diagrams (positive logic)





Pin numbers shown are for the DW, JT, and NT packages.



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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, V _{CC}			. 7 V
Input voltage, V _I : Control inputs			. 7 V
I/O ports			5.5 V
Operating free-air temperature range, TA:	SN54ALS646	−55°C to	125°C
	SN74ALS646A	0°C to	70°C
Storage temperature range		−65°C to	150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

recommended operating conditions

		SN	54ALS6	46	SN7	'4ALS64	6A	LINUT
		MIN	NOM	MAX	MIN	NOM	MAX	UNIT
VCC	Supply voltage	4.5	5	5.5	4.5	5	5.5	V
VIH	High-level input voltage	2			2			V
\vee_{IL}	Low-level input voltage			0.7			0.8	V
ЮН	High-level output current			-12			-15	mA
				12			24	4
lOL	Low-level output current						48‡	mA
fclock	Clock frequency	0		35	0		40	MHz
t _W	Pulse duration, CLKBA or CLKAB high or low	14.5			12.5			ns
t _{su}	Setup time, A before CLKAB↑ or B before CLKBA↑	15			10			ns
t _h	Hold time, A after CLKAB↑ or B after CLKBA↑	0			0			ns
TA	Operating free-air temperature	-55		125	0		70	°C

[‡] Applies only to the -1 version and only if V_{CC} is maintained between 4.75 V and 5.25

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

	DADAMETED	TEST COL	IDITIONS	SN	54ALS6	46	SN7	4ALS64	6A	LINUT
'	PARAMETER	TEST CON	IDITIONS	MIN	TYP	MAX	MIN	TYP†	MAX	UNIT
VIK		V _{CC} = 4.5 V,	$I_{I} = -18 \text{ mA}$			-1.2			-1.2	V
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V},$	$I_{OH} = -0.4 \text{ mA}$	V _{CC} -2			V _{CC} -2			
\/a			$I_{OH} = -3 \text{ mA}$	2.4	3.2		2.4	3.2		V
VOH		V _{CC} = 4.5 V	$I_{OH} = -12 \text{ mA}$	2						V
			$I_{OH} = -15 \text{ mA}$				2			
			I _{OL} = 12 mA		0.25	0.4		0.25	0.4	
VOL		V _{CC} = 4.5 V	I _{OL} = 24 mA					0.35	0.5	V
			$I_{OL} = 48 \text{ mA}^{\ddagger}$					0.35	0.5	
П	Control inputs	V _{CC} = 5.5 V	V _I = 7 V			0.1			0.1	mA
''	A or B ports	VCC = 3.5 V	V _I = 5.5 V			0.1			0.1	ША
	Control inputs	\/ F F \/	V: 0.7.V			20			20	^
ΊΗ	A or B ports§	V _{CC} = 5.5 V,	$V_{I} = 2.7 \text{ V}$			20			20	μΑ
	Control inputs	V 55V	V 0.4V			-0.2			-0.2	4
IIL	A or B ports§	V _{CC} = 5.5 V,	$V_{I} = 0.4 V$			-0.2			-0.2	mA
IOI		V _{CC} = 5.5 V,	V _O = 2.25 V	-20		-112	-30		-112	mA
			Outputs high		47	76		47	76	
Icc		V _{CC} = 5.5 V	Outputs low		55	88		55	88	mA
			Outputs disabled		55	88		55	88	

[†] All typical values are at $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$.

 $[\]ddagger$ Applies only to the -1 version and only if VCC is maintained between 4.75 V and 5.25 \$ For I/O ports, the parameters I_{IH} and I_{IL} include the off-state output current.

¹ The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, IOS.

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switching characteristics (see Figure 2)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _C C _L R1 R2 T _A	UNIT			
			SN54A	LS646	SN74AL	S646A	
			MIN	MAX	MIN	MAX	
f _{max}			35		40		MHz
^t PLH	CLKBA or CLKAB	A or B	10	35	7	30	ns
^t PHL	CENDA OF CENAD	AOIB	5	20	5	17	115
^t PLH	A or B	B or A	5	22	3	20	ns
^t PHL	AOID	2017	3	15	3	12	113
^t PLH	SBA or SAB‡	A or B	10	40	7	35	ns
^t PHL	(stored data low)	AOID	5	23	5	20	110
^t PLH	SBA or SAB‡	A or B	8	30	6	25	ns
^t PHL	(stored data high)	AOIB	5	24	5	20	115
^t PZH	ŌĒ	A or B	3	20	2	17	ns
^t PZL	OE	AOIB	5	22	4	20	115
^t PHZ	ŌĒ	A or B	1	12	1	10	ns
^t PLZ	OE	AOIB	1	20	2	16	115
^t PZH	DIR	A or B	5	38	3	30	ns
t _{PZL}	DIK	AUIB	5	30	4	25	115
^t PHZ	DIR	A or B	1	12	1	10	ns
^t PLZ	אוט	AUIB	2	21	2	16	115

[†] For conditions shown MIN or MAX, use the appropriate value specified under recommended operating conditions.

[‡] These parameters are measured with the internal output state of the storage register opposite that of the bus input.

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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, V _{CC}			7 V
Input voltage, V _I : Control inputs			7 V
I/O ports		5	5.5 V
Operating free-air temperature range, TA	: SN54ALS648	−55°C to 12	25°C
	SN74ALS648A	0°C to 7	70°C
Storage temperature range		-65°C to 15	50°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

recommended operating conditions

		SN	I54ALS6	48	SN7	'4ALS64	8A	UNIT
		MIN	NOM	MAX	MIN	NOM	MAX	UNII
Vcc	Supply voltage	4.5	5	5.5	4.5	5	5.5	V
V_{IH}	High-level input voltage	2			2			V
V_{IL}	Low-level input voltage			0.7			0.8	V
ЮН	High-level output current			-12			-15	mA
loL	Low-level output current			12			24	mA
fclock	Clock frequency	0		35	0		40	MHz
t _W	Pulse duration, CLKBA or CLKAB high or low	14.5			12.5			ns
t _{SU} Setup time, A before CLKAB↑ or B before CLKBA↑		15			10			ns
t _h	Hold time, A after CLKAB↑ or B after CLKBA↑	0			0			ns
T _A	T _A Operating free-air temperature			125	0		70	°C

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

	PARAMETER	TEST CO	NDITIONS	SN	54ALS6	48	SN7	'4ALS64	8A	UNIT	
	PARAMETER	1551 00	SNOTTIONS	MIN	TYP [†]	MAX	MIN	TYP [†]	MAX	UNII	
٧ıĸ		V _{CC} = 4.5 V,	$I_{I} = -18 \text{ mA}$			-1.2			-1.2	V	
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V},$	$I_{OH} = -0.4 \text{ mA}$	V _{CC} -2			V _{CC} -2				
\/a			$I_{OH} = -3 \text{ mA}$	2.4	3.2		2.4	3.2		V	
VOH		V _{CC} = 4.5 V	$I_{OH} = -12 \text{ mA}$	2						V	
			$I_{OH} = -15 \text{ mA}$				2				
\/0:	V _{CC} = 4.5 V		I _{OL} = 12 mA		0.25	0.4		0.25	0.4	V	
VOL			I _{OL} = 24 mA					0.35	0.5	V	
ı	Control inputs	V _{CC} = 5.5 V	V _I = 7 V			0.1			0.1	mA	
11	A or B ports	VCC = 5.5 V	V _I = 5.5 V			0.1			0.1	ША	
	Control inputs	V 55V	\/. 27\/			20			20	^	
ΊΗ	A or B ports‡	V _{CC} = 5.5 V,	V _I = 2.7 V		C = 5.5 V, V = 2.7 V		20			20	μΑ
Γ.	Control inputs	V 55V	\\ \ 0.4\\			-0.2			-0.2	0	
II∟	A or B ports‡	V _{CC} = 5.5 V,	$V_{I} = 0.4 V$			-0.2			-0.2	mA	
ΙΟ§		V _{CC} = 5.5 V,	V _O = 2.25 V	-20		-112	-30		-112	mA	
			Outputs high		47	76		47	76		
Icc		V _{CC} = 5.5 V	Outputs low		57	88		57	88	mA	
			Outputs disabled		57	88		57	88		

 $[\]uparrow$ All typical values are at V_{CC} = 5 V, T_A = 25°C.

[‡] For I/O ports, the parameters I_{IH} and I_{IL} include the off-state output current.

[§] The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, IOS.

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switching characteristics (see Figure 2)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _C C _L R1 R2 T _A	UNIT			
			SN54A	SN54ALS648 SN74ALS648A			
			MIN	MAX	MIN	MAX	
f _{max}			35		40		MHz
^t PLH	CLKBA or CLKAB	A or B	8	39	7	33	ns
^t PHL	CENDA OF CENAD	AOID	5	23	5	20	113
^t PLH	A or B	B or A	3	20	2	17	ns
^t PHL	AOID	DOIN	2	12	2	10	113
^t PLH	SBA or SAB‡	A or B	5	44	5	39	ns
^t PHL	(stored data low)	AUD	4	26	4	22	
^t PLH	SBA or SAB‡	A or B	6	30	6	25	ns
^t PHL	(stored data high)	AOID	6	25	6	21	113
^t PZH	ŌĒ	A or B	4	25	2	22	ns
^t PZL	OE	AOID	4	25	4	22	113
^t PHZ	ŌĒ	A or B	1	12	1	10	ne
^t PLZ	OE .	7015	2	21	2	15	ns
^t PZH	DIR	A or B	4	35	2	27	ns
^t PZL	DIIX	7015	3	25	3	19	110
^t PHZ	DIR	A or B	1	17	1	14	ns
t _{PLZ}	DIK	7016	2	22	2	15	115

[†] For conditions shown MIN or MAX, use the appropriate value specified under recommended operating conditions.

[‡] These parameters are measured with the internal output state of the storage register opposite that of the bus input.

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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, V _{CC}	7 V
Input voltage, V _I : Control inputs	7 V
I/O ports	5.5 V
Operating free-air temperature range, TA: SN54AS	646 –55°C to 125°C
SN74AS	646 0°C to 70°C
Storage temperature range	−65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

recommended operating conditions

			SI	N54AS64	ŀ6	SN	174AS64	6	UNIT
			MIN	NOM	MAX	MIN	NOM	MAX	UNII
VCC	Supply voltage		4.5	5	5.5	4.5	5	5.5	V
V_{IH}	High-level input voltage		2			2			V
V_{IL}	Low-level input voltage				0.8			0.8	V
loh	High-level output current				-12			-15	mA
IOL	Low-level output current				32			48	mA
fclock*	Clock frequency		0		75	0		90	MHz
+ *	Pulse duration	CLKBA or CLKAB high	6			5			ns
t _W *	ruise duration	CLKBA or CLKAB low	7			6			115
t _{su} *	Setup time, A before CLKAB↑ or B before	CLKBA↑	7			6			ns
th*	Hold time, A after CLKAB↑ or B before CL	KBA	0			0			ns
TA	Operating free-air temperature		-55		125	0		70	°C

^{*} On products compliant to MIL-STD-883, Class B, this parameter is based on characterization data but is not production tested.

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

	DADAMETED	TEST CO	NOITIONS	SN	154AS64	16	SN	174AS64	6	UNIT
	PARAMETER	1231 CO	NDITIONS	MIN	TYP [†]	MAX	MIN	TYP [†]	MAX	UNII
٧ıĸ		V _{CC} = 4.5 V,	I _I = -18 mA			-1.2			-1.2	V
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V},$	$I_{OH} = -2 \text{ mA}$	V _{CC} -2			V _{CC} -2			
\/~			$I_{OH} = -3 \text{ mA}$	2.4	3.2		2.4	3.2		V
VOH		V _{CC} = 4.5 V	$I_{OH} = -12 \text{ mA}$	2						V
			$I_{OH} = -15 \text{ mA}$				2			
\/a.		V _{CC} = 4.5 V	I _{OL} = 32 mA		0.25	0.5				V
VOL	_		I _{OL} = 48 mA					0.35	0.5	V
ļ	Control inputs	$V_{CC} = 5.5 \text{ V},$	V _I = 7 V			0.1			0.1	mA
ΙΙ	A or B ports	$V_{CC} = 5.5 \text{ V},$	V _I = 5.5 V			0.1			0.1	IIIA
	Control inputs	\/	V: 0.7.V			20			20	^
ΊΗ	A or B ports‡	V _{CC} = 5.5 V,	$V_{I} = 2.7 \text{ V}$			70			70	μΑ
	Control input	V 55V	V 0.4V			-0.5			-0.5	4
¹ı∟	A or B ports‡	V _{CC} = 5.5 V,	$V_{I} = 0.4 V$			-0.75			-0.75	mA
ΙΟ§	-	V _{CC} = 5.5 V,	V _O = 2.25 V	-30		-112	-30		-112	mA
			Outputs high		120	195		120	195	
ICC		V _{CC} = 5.5 V	Outputs low		130	211		130	211	mA
			Outputs disabled		130	211		130	211	

 $[\]uparrow$ All typical values are at V_{CC} = 5 V, T_A = 25 °C.

[‡] For I/O ports, the parameters I_{IH} and I_{IL} include the off-state output current.

[§] The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, IOS.

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switching characteristics (see Figure 2)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _C C _L R1 R2 T _A	UNIT			
			SN54A	\S646	SN74A	S646	
			MIN	MAX	MIN	MAX	
fmax*			75		90		MHz
tPLH	CLKBA or CLKAB	A or B	2	9.5	2	8.5	ns
t _{PHL}	CENDA OF CENAD	AOIB	2	10	2	9	ns
^t PLH	A or B	B or A	2	11.5	2	9	ns
^t PHL	AUD	DUIA	1	8	1	7	113
^t PLH	SBA or SAB‡	A or B	2	13.5	2	11	ns
^t PHL	SBA UI SAB+	AOID	2	11	2	9	
^t PZH	ŌĒ	A or B	2	11	2	9	ns
tPZL	OE .	A 01 B	3	15	3	14	113
^t PHZ	ŌĒ	A or B	2	11	2	9	ns
^t PLZ	OE	AUD	2	11	2	9	113
^t PZH	DIR	A or B	3	21	3	16	ns
t _{PZL}	DIIX	7015	3	24	3	18	113
[†] PHZ	DIR	A or B	2	12	2	10	ns
^t PLZ	אום	A 01 B	2	12	2	10	115

^{*} On products compliant to MIL-STD-883, Class B, this parameter is based on characterization data but is not production tested.

[†] For conditions shown MIN or MAX, use the appropriate value specified under recommended operating conditions.

[‡] These parameters are measured with the internal output state of the storage register opposite that of the bus input.

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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, V _{CC}	7 V
Input voltage, V _I : Control inputs	7 V
I/O ports	5.5 V
Operating free-air temperature range, T _A : SN74AS648 0	°C to 70°C
Storage temperature range	C to 150°C

recommended operating conditions

			SI	N74AS64	18	LINUT
			MIN	NOM	MAX	UNIT
VCC	Supply voltage		4.5	5	5.5	V
V _{IH}	High-level input voltage		2			V
VIL	Low-level input voltage				0.8	V
lOH	High-level output current				-15	mA
loL	Low-level output current				48	mA
fclock	Clock frequency		0		90	MHz
	Pulse duration	CLKBA or CLKAB high	5			
t _W	Pulse duration	CLKBA or CLKAB low	6			ns
t _{su}	Setup time, A before CLKAB↑ or B before CLKBA↑		6			ns
th	Hold time, A after CLKAB↑ or B before CLKBA		0			ns
TA	Operating free-air temperature		0		70	°C

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

	DADAMETED	TEST COND	NTIONS	SN	174AS64	18	LINUT
	PARAMETER	TEST COND	ITIONS	MIN	TYP‡	MAX	UNIT
٧ıK		$V_{CC} = 4.5 V,$	$I_{I} = -18 \text{ mA}$			-1.2	V
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V},$	$I_{OH} = -2 \text{ mA}$	V _{CC} -2			
۷он		V 45V	IOH = -3 mA	2.4	3.2		V
		$V_{CC} = 4.5 \text{ V}$	$I_{OH} = -15 \text{ mA}$	2			
VOL		$V_{CC} = 4.5 V,$	I _{OL} = 48 mA		0.35	0.5	V
1.	Control inputs	Vac EEV	V _I = 7 V			0.1	A
'1	A or B ports	VCC = 5.5 V	V _I = 5.5 V			0.1	mA
	Control inputs		V 07V			20	
lін	A or B ports§	$V_{CC} = 5.5 V,$	V _I = 2.7 V			70	μΑ
	Control input					-0.5	
IIL	A or B ports§	$V_{CC} = 5.5 V,$	V _I = 0.4 V			-0.75	mA
Io¶		V _{CC} = 5.5 V,	V _O = 2.25 V	-30		-112	mA
			Outputs high		110	185	
Icc		$V_{CC} = 5.5 V$	Outputs low		120	195	mA
			Outputs disabled		120	195	

 $[\]ddagger$ All typical values are at V_{CC} = 5 V, T_A = 25 °C.

The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, IOS.



[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

[§] For I/O ports, the parameters I_{IH} and I_{IL} include the off-state output current.

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switching characteristics (see Figure 2)

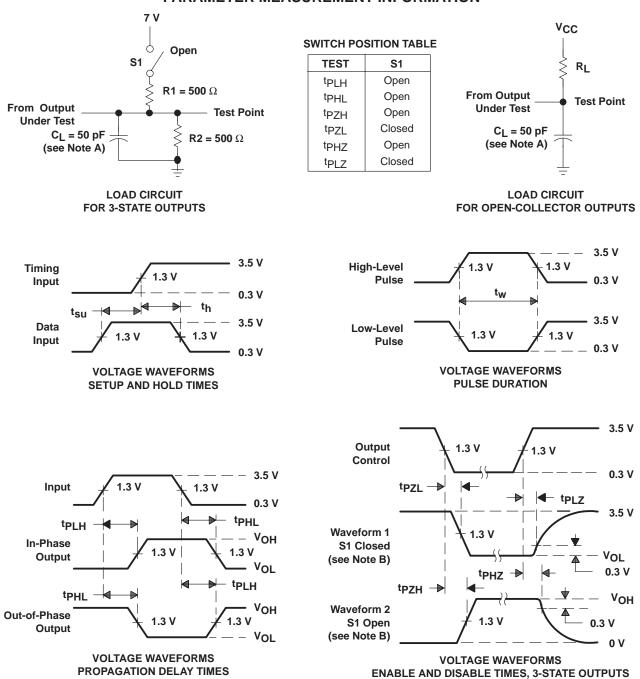
PARAMETER	FROM (INPUT)	TO (OUTPUT)	$V_{CC} = 4.5$ $C_L = 50 \text{ pF}$ $R1 = 500 \Omega$ $R2 = 500 \Omega$ $T_A = \text{MIN to}$ $SN74A$	UNIT	
		MIN	MAX		
fmax			90		MHz
t _{PLH}	CLKBA or CLKAB	A or B	2	8.5	ns
^t PHL	CENDA OI CENAD	AUIB	2	9	115
t _{PLH}	A or B	B or A	2	8	ns
[†] PHL	7010	D 01 A	1	7	113
^t PLH	SBA or SAB‡	A or B	2	11	ns
[†] PHL	SBA OF SAB+	7010	2	9	113
^t PZH	OE	A or B	2	9	ns
^t PZL	OE .	A 01 B	3	15	115
^t PHZ	ŌĒ	A or B	2	9	ns
^t PLZ	OE .	A 01 B	2	9	115
^t PZH	DIR	A or B	3	16	ns
tPZL	DIK	AUIB	3	18	115
t _{PHZ}	DIR	A or B	2	10	ns
^t PLZ	DIK	AUID	2	10	1115

[†] For conditions shown MIN or MAX, use the appropriate value specified under recommended operating conditions.

[‡] These parameters are measured with the internal output state of the storage register opposite that of the bus input.

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PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, $Z_O = 50 \ \Omega$, $t_f \leq$ 2 ns, $t_f \leq$ 2 ns.
- D. The outputs are measured one at a time with one transition per measurement.

Figure 2. Load Circuits and Voltage Waveforms





PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
5962-87595013A	ACTIVE	LCCC	FK	28	1	TBD	POST-PLATE	N / A for Pkg Type
5962-8759501KA	ACTIVE	CFP	W	24	1	TBD	A42	N / A for Pkg Type
5962-8759501LA	ACTIVE	CDIP	JT	24	1	TBD	A42 SNPB	N / A for Pkg Type
5962-89956013A	ACTIVE	LCCC	FK	28	1	TBD	POST-PLATE	N / A for Pkg Type
5962-8995601LA	ACTIVE	CDIP	JT	24	1	TBD	A42 SNPB	N / A for Pkg Type
5962-9052301LA	ACTIVE	CDIP	JT	24	1	TBD	A42 SNPB	N / A for Pkg Type
SN54AS646JT	ACTIVE	CDIP	JT	24	1	TBD	A42 SNPB	N / A for Pkg Type
SN74ALS646A-1DW	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74ALS646A-1DWE4	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74ALS646A-1DWG4	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74ALS646A-1DWR	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74ALS646A-1DWRE4	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74ALS646A-1DWRG4	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74ALS646A-1NT	ACTIVE	PDIP	NT	24	15	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
SN74ALS646A-1NTE4	ACTIVE	PDIP	NT	24	15	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
SN74ALS646ADW	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74ALS646ADWE4	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74ALS646ADWG4	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74ALS646ADWR	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74ALS646ADWRE4	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74ALS646ADWRG4	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74ALS646ANT	ACTIVE	PDIP	NT	24	15	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
SN74ALS646ANTE4	ACTIVE	PDIP	NT	24	15	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
SN74ALS648ADW	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74ALS648ADWE4	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74ALS648ADWG4	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74ALS648ADWR	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74ALS648ADWRE4	ACTIVE	SOIC	DW	24	2000	Green (RoHS &	CU NIPDAU	Level-1-260C-UNLIM





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Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
						no Sb/Br)		
SN74ALS648ADWRG4	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74ALS648ANT	ACTIVE	PDIP	NT	24	15	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
SN74ALS648ANTE4	ACTIVE	PDIP	NT	24	15	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
SN74AS646DW	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AS646DWE4	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AS646DWG4	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AS646DWR	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AS646DWRE4	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AS646DWRG4	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AS646NT	ACTIVE	PDIP	NT	24	15	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
SN74AS646NTE4	ACTIVE	PDIP	NT	24	15	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
SN74AS648DW	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AS648DWE4	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AS648DWG4	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AS648DWR	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AS648DWRE4	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AS648DWRG4	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AS648NT	ACTIVE	PDIP	NT	24	15	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
SN74AS648NT3	OBSOLETE	PDIP	NT	24		TBD	Call TI	Call TI
SN74AS648NTE4	ACTIVE	PDIP	NT	24	15	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
SNJ54ALS646FK	ACTIVE	LCCC	FK	28	1	TBD	POST-PLATE	N / A for Pkg Type
SNJ54ALS646JT	ACTIVE	CDIP	JT	24	1	TBD	A42 SNPB	N / A for Pkg Type
SNJ54ALS646W	OBSOLETE	CFP	W	24		TBD	Call TI	Call TI
SNJ54ALS648FK	OBSOLETE	LCCC	FK	24		TBD	Call TI	Call TI
SNJ54ALS648JT	ACTIVE	CDIP	JT	24	1	TBD	A42 SNPB	N / A for Pkg Type
SNJ54ALS648W	OBSOLETE	CFP	W	24		TBD	Call TI	Call TI
SNJ54AS646FK	ACTIVE	LCCC	FK	28	1	TBD	POST-PLATE	N / A for Pkg Type
SNJ54AS646JT	ACTIVE	CDIP	JT	24	1	TBD	A42 SNPB	N / A for Pkg Type
SNJ54AS646W	ACTIVE	CFP	W	24	1	TBD	A42	N / A for Pkg Type



PACKAGE OPTION ADDENDUM

18-Sep-2008

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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OTHER QUALIFIED VERSIONS OF SN54ALS646, SN54ALS648, SN54AS646, SN74AS646:

Catalog: SN74ALS646, SN74ALS648

NOTE: Qualified Version Definitions:

Catalog - TI's standard catalog product



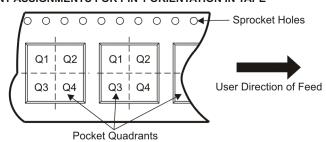
TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74ALS646A-1DWR	SOIC	DW	24	2000	330.0	24.4	10.75	15.7	2.7	12.0	24.0	Q1
SN74ALS646ADWR	SOIC	DW	24	2000	330.0	24.4	10.75	15.7	2.7	12.0	24.0	Q1
SN74ALS648ADWR	SOIC	DW	24	2000	330.0	24.4	10.75	15.7	2.7	12.0	24.0	Q1
SN74AS646DWR	SOIC	DW	24	2000	330.0	24.4	10.75	15.7	2.7	12.0	24.0	Q1
SN74AS648DWR	SOIC	DW	24	2000	330.0	24.4	10.75	15.7	2.7	12.0	24.0	Q1





*All dimensions are nominal

All difficultions are norminal							
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74ALS646A-1DWR	SOIC	DW	24	2000	346.0	346.0	41.0
SN74ALS646ADWR	SOIC	DW	24	2000	346.0	346.0	41.0
SN74ALS648ADWR	SOIC	DW	24	2000	346.0	346.0	41.0
SN74AS646DWR	SOIC	DW	24	2000	346.0	346.0	41.0
SN74AS648DWR	SOIC	DW	24	2000	346.0	346.0	41.0

FK (S-CQCC-N**)

28 TERMINAL SHOWN

LEADLESS CERAMIC CHIP CARRIER



NOTES: A. All linear dimensions are in inches (millimeters).

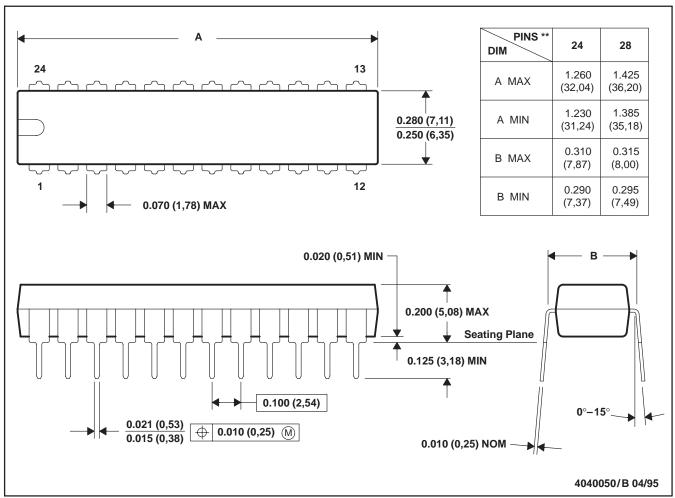
- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a metal lid.
- D. The terminals are gold plated.
- E. Falls within JEDEC MS-004



NT (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

24 PINS SHOWN

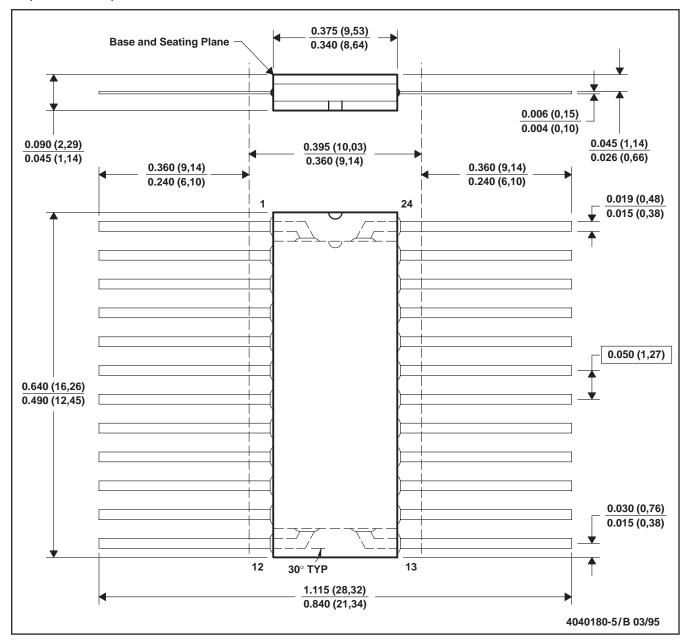


NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

W (R-GDFP-F24)

CERAMIC DUAL FLATPACK



- NOTES: A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. This package can be hermetically sealed with a ceramic lid using glass frit.
 - D. Falls within MIL-STD-1835 GDFP2-F24 and JEDEC MO-070AD
 - E. Index point is provided on cap for terminal identification only.



DW (R-PDSO-G24)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-013 variation AD.



JT (R-GDIP-T**)

24 LEADS SHOWN

CERAMIC DUAL-IN-LINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification.
- E. Falls within MIL STD 1835 GDIP3-T24, GDIP4-T28, and JEDEC MO-058 AA, MO-058 AB

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